



DDTA (R2-ONLY SERIES) **UA**

PNP PRE-BIASED SMALL SIGNAL SURFACE MOUNT TRANSISTOR

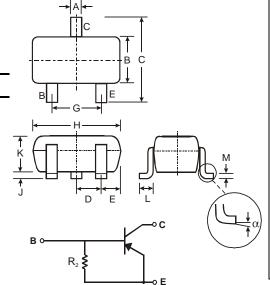
Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTC)
- Built-In Biasing Resistor, R2 only
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device, (Note 3 and 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking: Date Code and Type Code, See Page 3
- Type Code: See Table Below
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)

P/N	R2 (NOM)	Type Code
DDTA114GUA	10KΩ	P26
DDTA124GUA	22Κ Ω	P27
DDTA144GUA	47 K Ω	P28
DDTA115GUA	100KΩ	P29



SOT-323								
Dim	Min	Max						
Α	0.25	0.40						
В	1.15	1.35						
С	2.00 2.20							
D	0.65 Nominal							
E	0.30	0.40						
G	1.20	1.40						
Н	1.80	2.20						
J	0.0	0.10						
K	0.90	1.00						
L	0.25	0.40						
М	0.10	0.18						
α	0°	8°						
All Dimensions in mm								

SCHEMATIC DIAGRAM

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	-50	V	
Collector-Emitter Voltage	V _{CEO}	-50	V	
Emitter-Base Voltage	V _{EBO}	-5	V	
Collector Current	I _C (Max)	-100	mA	
Power Dissipation	P _d	200	mW	
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{ heta JA}$	625	°C/W	
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C	

Notes:

- 1. Mounted on FR4 PC Board with recommended pad layout as shown on Diodes Inc., suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf
- 2. No purposefully added lead.
- 3. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with date code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to date code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

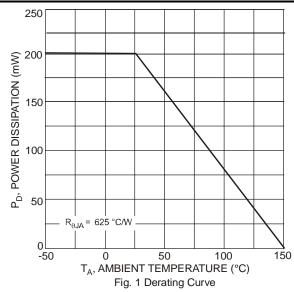


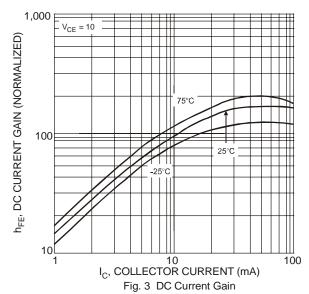
Electrical Characteristics @T_A = 25°C unless otherwise specified

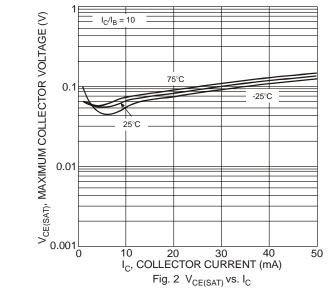
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	Collector-Base Breakdown Voltage		-50		_	V	$I_C = -50\mu A$
Collector-Emitter Breakdown Voltage	е	BV _{CEO}	-50			V	$I_C = -1mA$
Emitter-Base Breakdown Voltage		BV _{EBO}	5		_	>	I _E = -720μA, DDTA114GUA I _E = -330μA, DDTA124GUA I _E = -160μA, DDTA144GUA I _E = -72μA, DDTA115GUA
Collector Cutoff Current		I _{CBO}			-0.5	μΑ	$V_{CB} = -50V$
Emitter Cutoff Current	DDTA114GUA DDTA124GUA DDTA144GUA DDTA115GUA	I _{EBO}	-300 -140 -65 -30	_	-580 -260 -130 -58	μА	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}			-0.3	٧	$I_C = -10mA$, $I_B = -0.5mA$
DDTA114GUA DDTA1124GUA DDTA124GUA DDTA144GUA DDTA115GUA		h _{FE}	30 56 68 82	_	_	_	$I_C = -5mA$, $V_{CE} = -5V$
Bleeder Resistor (R ₂) Tolerance		ΔR_2	-30	_	+30	%	_
Gain-Bandwidth Product*		f⊤	_	250	_	MHz	$V_{CE} = -10V, I_{E} = 5mA,$ f = 100MHz

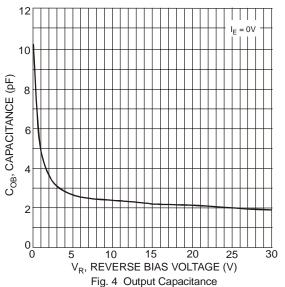
^{*} Transistor - For Reference Only

Typical Curves – DDTA114GUA

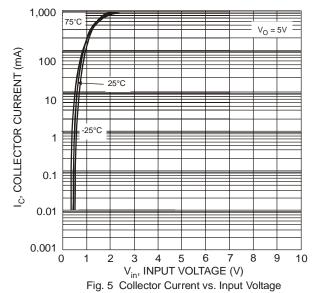


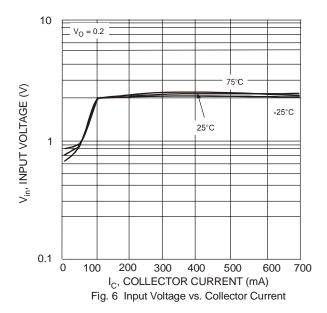










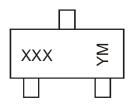


Ordering Information (Note 4 & 5)

Device	Packaging	Shipping
DDTA114GUA-7-F	SOT-323	3000/Tape & Reel
DDTA124GUA-7-F	SOT-323	3000/Tape & Reel
DDTA144GUA-7-F	SOT-323	3000/Tape & Reel
DDTA115GUA-7-F	SOT-323	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code, See Table on Page 1

YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	200	6	2007		2008		2009			2011		2012	
Code	Т		U		V W		Х		Υ	Z			
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec	
Code	1	2	3	4	5	6	7	8	9	0	Ν	D	

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